DNSemi

MARKING DIAGRAMS

TinyLogic HST 2-Input OR Gate

NC7ST32

Description

The NC7ST32 is a single 2-Input high performance CMOS OR Gate, with TTL-compatible inputs. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. High gain circuitry offers high noise immunity and reduced sensitivity to input edge rate. The TTL-compatible inputs facilitate TTL to NMOS / CMOS interfacing. Device performance is similar to MM74HCT but with 1/2 the output current drive of HC / HCT.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPak[™] Leadless Package
- High Speed: $t_{PD} < 7$ ns Typ, $V_{CC} = 5$ V, $C_L = 15$ pF
- Low Quiescent Power: $I_{CC} < 1 \mu A$ Typ, $V_{CC} = 5.5 V$
- Balanced Output Drive: 2 mA IOL, -2 mA IOH
- TTL-compatible Inputs
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

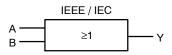
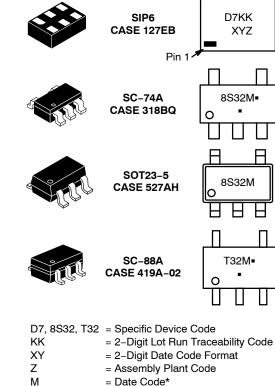


Figure 1. Logic Symbol



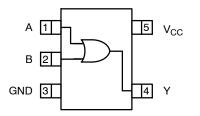
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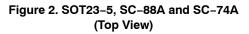
*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 4 of this data sheet.

Pin Configurations





PIN DESCRIPTIONS

Pin Name	Description
A, B	Inputs
Y	Output
NC	No Connect

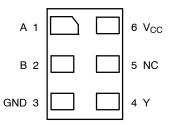


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE (Y = A + B)

Inp	Output	
А	В	Y
L	L	L
L	н	Н
Н	L	Н
Н	Н	Н

H = HIGH Logic Level L = LOW Logic Level

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
۱ _{IK}	DC Input Diode Current	V _{IN} < 0 V	_	-20	mA
		$V_{IN} > V_{CC}$	-	+20	
V _{IN}	DC Input Voltage		-0.5	V _{CC} + 0.5	V
I _{OK}	DC Output Diode Current V _{OUT} < 0 V		-	-20	mA
		V _{OUT} > V _{CC}	-	+20	
V _{OUT}	Output Voltage		-0.5	V _{CC} + 0.5	V
I _{OUT}	DC Output Source or Sink Current	t	-	±12.5	mA
$I_{CC} \text{ or } I_{GND}$	DC V _{CC} or Ground Current per Su	ipply Pin	-	±25	mA
T _{STG}	Storage Temperature		-65	+150	°C
Τ _J	Junction Temperature	Junction Temperature		+150	°C
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	+260	°C
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		4.5	5.5	V
V _{IN}	Input Voltage		0	V _{CC}	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 5.0 V	0	10	ns/V
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

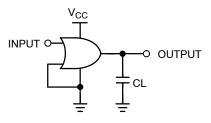
				Т	A = +25°0	2	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	4.5 – 5.5		2.0	-	-	2.0	-	V
V _{IL}	LOW Level Input Voltage	4.5 – 5.5		-	-	0.8	-	0.8	V
V _{OH}	HIGH Level Output Voltage	4.5	I_{OH} = –20 $\mu A_{,}~V_{IN}$ = V_{IH} or V_{IL}	4.4	4.5	-	4.4	-	V
		4.5	I _{OH} = -2 mA	4.18	4.35	-	4.13	-	
V _{OL}	LOW Level Output Voltage	4.5	I_{OL} = 20 $\mu A,V_{IN}$ = V_{IH} or V_{IL}	-	0	0.1	_	0.1	V
		4.5	I _{OL} = 2 mA	-	0.10	0.26	_	0.33	
I _{IN}	Input Leakage Current	5.5	$0~V \leq V_{IN} \leq 5.5~V$	-	-	±0.1	_	±1.0	μA
I _{CC}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND	-	-	1.0	-	10.0	μA
I _{CCT}	I _{CC} per Input	5.5	One Input V_{IN} = 0.5 V or 2.4 V, Other Input V_{CC} or GND	-	-	2.0	-	2.9	mA

AC ELECTRICAL CHARACTERISTICS

					T _A = +25°0	2	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay (Figure 4, 6)	5.0	C _L = 15 pF	-	4.3	12	-	-	ns
				-	6.1	17	-	-	
		4.5	C _L = 50 pF	-	6.5	16	-	20	
				-	12	27	-	31	
		5.5		-	5.4	14	-	18	
				-	10.7	26	-	30	
t _{TLH} , t _{THL}	Output Transition Time	5.0	C _L = 15 pF	-	4	10	-	-	ns
	(Figure 4, 6)	4.5	C _L = 50 pF	-	11	25	-	31	
		5.5		-	10	21	-	26	
C _{IN}	Input Capacitance	Open		-	2	10	-	-	pF
C _{PD}	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	-	6	-	-	-	pF

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current. Current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 5) C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit

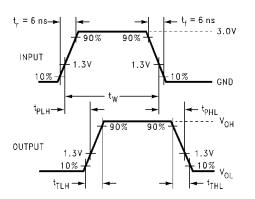
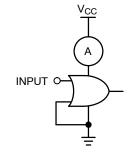


Figure 6. AC Waveforms



Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.



ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]
NC7ST32M5X	8S32	SC-74A	3000 / Tape & Reel
NC7ST32M5X-L22090	8S32	SOT23-5	3000 / Tape & Reel
NC7ST32P5X	T32	SC-88A	3000 / Tape & Reel
NC7ST32P5X-L22057	T32	SC-88A	3000 / Tape & Reel
NC7ST32L6X	D7	SIP6, MicroPak	5000 / Tape & Reel
NC7ST32L6X-L22175	D7	SIP6, MicroPak	5000 / Tape & Reel

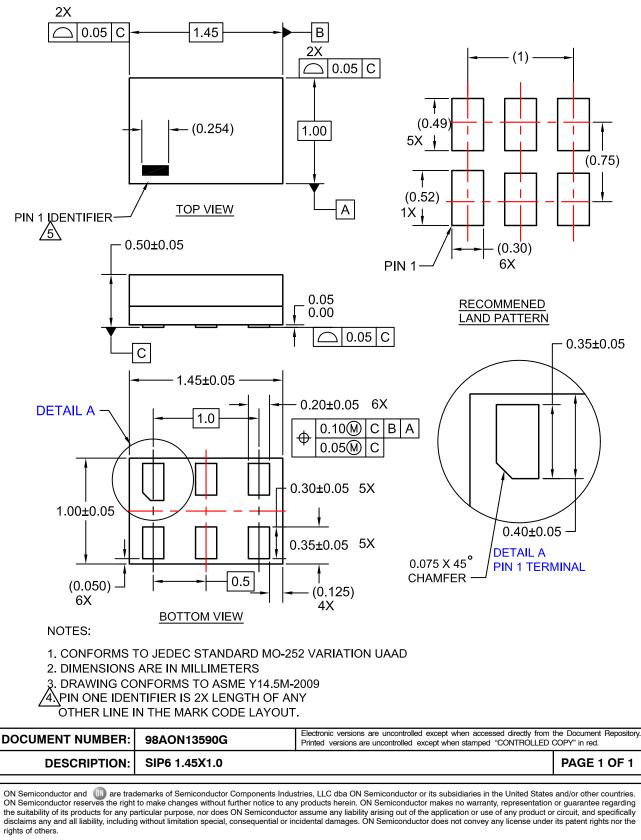
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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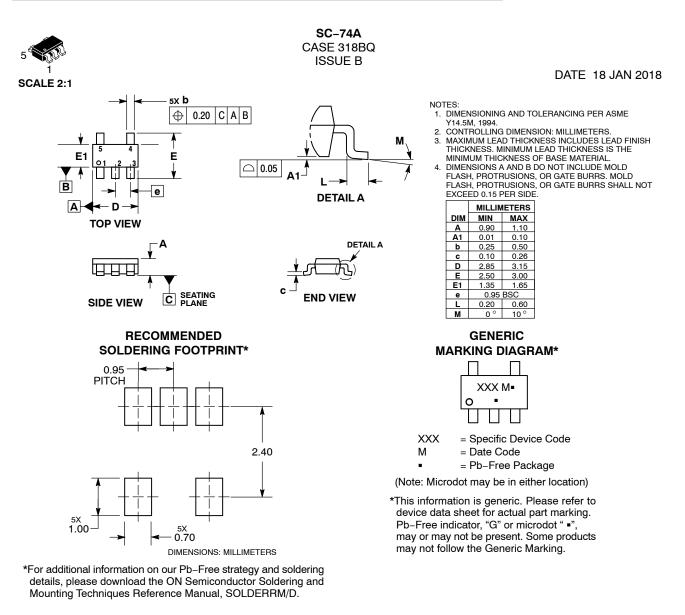


SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016







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DATE 11 APR 2023

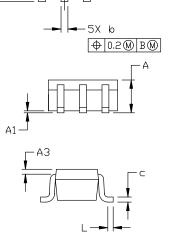


SCALE 2:1

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

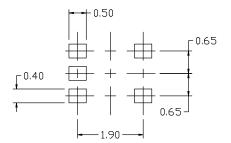
NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE. NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.



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F1



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our
Pb-Free strategy and soldering details,
please download the DN Semiconductor
Soldering and Mounting Techniques
Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS			
ויונע	MIN.	NDM.	MAX,	
A	0.80	0.95	1.10	
A1			0.10	
A3		0.20 REF		
b	0.10	0.20	0,30	
C	0.10		0,25	
D	1.80	2.00	5.20	
E	2.00	2.10	5.20	
E1	1.15	1.25	1.35	
e	0.65 BSC			
L	0.10	0.15	0.30	

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE PIN 1. ANODE PIN 1. ANODE 1 PIN 1. SOURCE 1 PIN 1. CATHODE 2. EMITTER 2. EMITTER 2. N/C 2. DRAIN 1/2 2. COMMON ANODE 3. BASE 3. BASE 3. ANODE 2 3. SOURCE 1 3. CATHODE 2 4. COLLECTOR 4. COLLECTOR 4. CATHODE 2 4. GATE 1 4. CATHODE 3 5. COLLECTOR 5. CATHODE 5. CATHODE 1 5. GATE 2 5. CATHODE 4 STYLE 6: STYLE 7: STYLE 8: STYLE 9: Note: Please refer to datasheet for style callout. If style type is not callout. COLLECTOR 3. EMITTER 1 3. BASE 3. N/C 3. ANODE 2 CATHODE 4. COLLECTOR 4. COLLECTOR 4. BASE 4. ANODE 3 out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. If style type is not callout. COLLECTOR 4. COLLECTOR 4. COLLECTOR 5. EMITTER 5. ANODE out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. COLLECTOR 5. COLLECTOR 2/BASE 1 5. COLLECTOR 5. EMITTER 5. ANODE out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. If style type is not call	DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1
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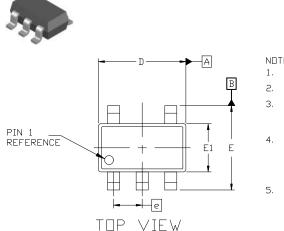
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XXX = Specific Device Code

M = Date Code = Pb-Free Package

⁽Note: Microdot may be in either location)



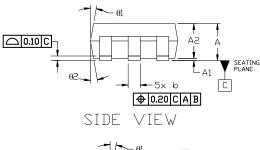


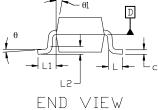


DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





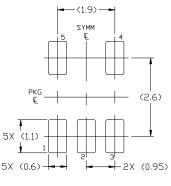
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS				
DIM	MIN.	NDM.	MAX.		
А	0.90	—	1.45		
A1	0.00	_	0.15		
A2	0.90	1.15	1.30		
b	0.30	—	0.50		
С	0.08	—	0.22		
D	2.90 BSC				
E	2.80 BSC				
E1	1.60 BSC				
e	0.95 BSC				
L	0.30	0.45	0.60		
L1	0.60 REF				
L2	0.25 REF				
θ	0*	4°	8*		
θ1	0°	10°	15°		
θ2	0*	10°	15°		



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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